

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)
Shunpei YAMAZAKI et al.)
Serial No. 09/118,010) Art Unit: 2822
Filed: July 17, 1998) Examiner: M. Guerrero
For: SEMICONDUCTOR DEVICE, METHOD)
OF FABRICATING SAME, AND)
ELECTROOPTICAL DEVICE) Date: February 14, 2002

PRELIMINARY AMENDMENT

Honorable Commissioner for Patents and Trademarks
Washington, D.C. 20231

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FEB 14 2002
OFFICE OF PETITIONS

Sir:

Please preliminarily amend the subject application as follows:

IN THE CLAIMS:

Please add new claims 47-73 as follows:

- 45
--47. A semiconductor device comprising:
 a resinous substrate having an uneven surface;
 a resinous layer provided on said uneven surface of said resinous
 substrate and having a planarized surface; and
 a thin-film transistor provided on said planarized surface of said
 resinous layer;
 an interlayer insulating layer comprising a resinous material provided
 over said thin-film transistor; and